## **AMENDMENTS TO THE CLAIMS**

This listing of claims will replace all prior versions, and listings, of claims in the application:

## **Listing of Claims**

Claim 1 (Currently amended): A high-frequency heating apparatus for driving a magnetron, comprising:

a DC power supply including an AC power supply, a rectifier circuit for rectifying a voltage of the AC power supply, and a smoothing capacitor for smoothing an output voltage of the rectifier circuit;

a series circuit including two semiconductor switching devices, the series circuit being connected in parallel to the [[AC]] <u>DC</u> power supply;

a resonance circuit connected to a primary winding of a leakage transformer and a capacitor, one end of the resonance circuit being connected to a middle point of the series circuit in an AC equivalent circuit while the other end of the resonance circuit is connected to one end of the [[AC]] <u>DC</u> power supply;

- a drive unit for driving each of the semiconductor switching devices;
- a rectifier unit connected to a secondary winding of the leakage transformer;
- a magnetron connected to the rectifier unit; and
- a dead time generation circuit for turning off the semiconductor switching devices concurrently,

wherein the drive unit has a function of limiting the lowest frequency of a frequency with which the semiconductor switching devices are driven, so that the lowest frequency is set to be

high a first frequency at the beginning of operation of the high-frequency heating apparatus, and

the lowest frequency is set to be lower a second frequency which is lower than the first

frequency gradually thereafter.

Claim 2 (Currently amended): A high-frequency heating apparatus for driving a

magnetron, comprising:

a DC power supply including an AC power supply, a rectifier circuit for rectifying a

voltage of the AC power supply, and a smoothing capacitor for smoothing an output voltage of

the rectifier circuit;

two series circuits each including two semiconductor switching devices, each of the

series circuits being connected in parallel to the [[AC]] DC power supply;

a resonance circuit connected to a primary winding of a leakage transformer and a

capacitor, one end of the resonance circuit being connected to a middle point of one of the series

circuits while the other end of the resonance circuit is connected to a middle point of the other

series circuit;

a drive unit for driving each of the semiconductor switching devices;

a rectifier unit connected to a secondary winding of the leakage transformer;

a magnetron connected to the rectifier unit; and

a dead time generation circuit for turning off the semiconductor switching devices

concurrently,

wherein the drive unit has a function of limiting the lowest frequency of a frequency with

which the semiconductor switching devices are driven, so that the lowest frequency is set to be

high a first frequency at the beginning of operation of the high-frequency heating apparatus, and

Page 3 of 18

the lowest frequency is set to be lower a second frequency which is lower than the first

frequency gradually thereafter.

Claim 3 (Currently amended): A high-frequency heating apparatus for driving a

magnetron, comprising:

a DC power supply including an AC power supply, a rectifier circuit for rectifying a

voltage of the AC power supply, and a smoothing capacitor for smoothing an output voltage of

the rectifier circuit;

a series circuit including two semiconductor switching devices, the series circuit being

connected in parallel to the [[AC]] <u>DC</u> power supply;

a resonance circuit connected to a primary winding of a leakage transformer and a

capacitor, the resonance circuit being connected in parallel to one of the semiconductor

switching devices;

a drive unit for driving each of the semiconductor switching devices;

a rectifier unit connected to a secondary winding of the leakage transformer;

a magnetron connected to the rectifier unit; and

a dead time generation circuit for turning off the semiconductor switching devices

concurrently,

wherein the drive unit has a function of limiting the lowest frequency of a frequency with

which the semiconductor switching devices are driven, so that the lowest frequency is set to be

high a first frequency at the beginning of operation of the high-frequency heating apparatus, and

the lowest frequency is set to be lower a second frequency which is lower than the first

frequency gradually thereafter.

Page 4 of 18

Claim 4 (Previously presented): The high-frequency heating apparatus according to

claim 1, further comprising:

an error signal generation circuit for generating an error signal from a difference between

an input current of the AC power supply and a reference current; and

a frequency-modulated signal generation circuit for correcting a rectified voltage/rectified

current obtained by rectifying the AC power supply, based on an output (error signal) of the error

signal generation circuit, an output of the frequency-modulated signal generation circuit being

supplied to the dead time generation circuit;

wherein a lowest frequency limiting circuit is inserted between the frequency-modulated

signal generation circuit and the dead time generation circuit, the lowest frequency limiting

circuit supplies a limited frequency to the dead time generation circuit based on the output signal

of the frequency-modulated signal generation circuit so that a set frequency of the lowest

frequency limiting circuit is set to be higher than the output of the frequency-modulated signal

generation circuit at the beginning of operation of the aforementioned high-frequency heating

apparatus, and in accordance with time having passed since the beginning of operation, the

limited frequency is lowered gradually, while with lowering of the limited frequency, a signal

higher in switching frequency of the limited frequency and the output signal of the frequency-

modulated signal generation circuit is selected as a signal to be supplied to the dead time

generation circuit in accordance with time having passed, so that the selected signal is changed

over gradually to the output signal of the frequency-modulated signal generation circuit.

Page 5 of 18

Claim 5 (Original): The high-frequency heating apparatus according to claim 4, wherein

the lowest frequency limiting circuit has a capacitor, the capacitor is charged during suspension

of the high-frequency heating apparatus, and as soon as the high-frequency heating apparatus

begins to operate, a voltage of the capacitor is supplied to the dead time generation circuit, and

charges accumulated in the capacitor are discharged.

Claim 6 (Previously presented): The high-frequency heating apparatus according to

claim 4, wherein the dead time generation circuit generates a fixed or marginally increased dead

time regardless of a switching frequency.

Claim 7 (Previously presented): The high-frequency heating apparatus according to

claim 1, wherein the dead time generation circuit generates a dead time increased in accordance

with increase of a switching frequency.

Claim 8 (Original): The high-frequency heating apparatus according to claim 7, wherein

the dead time generation circuit fixes or marginally increases the dead time at a switching

frequency not higher than a predetermined frequency.

Claim 9 (Previously presented): The high-frequency heating apparatus according to

claim 7, wherein the dead time generation circuit suddenly increases the dead time at a switching

frequency not lower than a predetermined frequency.

Claims 10-12 (Canceled)

Page 6 of 18

Claim 13 (Previously presented): The high-frequency heating apparatus according to

claim 1, wherein the dead time generation circuit generates a dead time based on positive and

negative offset voltages each varying with a first inclination in proportion to increase of a

switching frequency and varying with a second inclination when the switching frequency reaches

a predetermined frequency or higher.

Claim 14 (Currently amended): The high-frequency heating apparatus according to claim

1, wherein the dead time generation circuit includes a VCC power supply, a duty control power

supply, a first current varying in proportion to a switching frequency, a second current beginning

to flow flowing at a predetermined frequency at beginning and varying in proportion to the

switching frequency, a third current obtaining by and multiplying a combining current of the two

currents by a predetermined coefficient, and a upper and lower potential generation unit for

generating [[two]] a set of upper and lower potentials obtained by adding positive and negative

offset voltages proportional to the third current, to the duty control power supply respectively,

and a dead time is generated based on the two set of upper and lower potentials.

Claim 15 (Canceled)

Claim 16 (Previously presented): The high-frequency heating apparatus according to

claim 2, further comprising:

an error signal generation circuit for generating an error signal from a difference between

an input current of the AC power supply and a reference current; and

Page 7 of 18

a frequency-modulated signal generation circuit for correcting a rectified voltage/rectified

current obtained by rectifying the AC power supply, based on an output (error signal) of the error

signal generation circuit, an output of the frequency-modulated signal generation circuit being

supplied to the dead time generation circuit;

wherein a lowest frequency limiting circuit is inserted between the frequency-modulated

signal generation circuit and the dead time generation circuit, the lowest frequency limiting

circuit supplies a limited frequency to the dead time generation circuit based on the output signal

of the frequency-modulated signal generation circuit so that a set frequency of the lowest

frequency limiting circuit is set to be higher than the output of the frequency-modulated signal

generation circuit at the beginning of operation of the aforementioned high-frequency heating

apparatus, and in accordance with time having passed since the beginning of operation, the

limited frequency is lowered gradually, while with lowering of the limited frequency, a signal

higher in switching frequency of the limited frequency and the output signal of the frequency-

modulated signal generation circuit is selected as a signal to be supplied to the dead time

generation circuit in accordance with time having passed, so that the selected signal is changed

over gradually to the output signal of the frequency-modulated signal generation circuit.

Claim 17 (Currently amended): The high-frequency heating apparatus according to claim

[[12]] 16, wherein the lowest frequency limiting circuit has a capacitor, the capacitor is charged

during suspension of the high-frequency heating apparatus, and as soon as the high-frequency

heating apparatus begins to operate, a voltage of the capacitor is supplied to the dead time

generation circuit, and charges accumulated in the capacitor are discharged.

Page 8 of 18

Claim 18 (Currently amended): The high-frequency heating apparatus according to claim

[[12]] 16, wherein the dead time generation circuit generates a fixed or marginally increased

dead time regardless of a switching frequency.

Claim 19 (Previously presented): The high-frequency heating apparatus according to

claim 2, wherein the dead time generation circuit generates a dead time increased in accordance

with increase of a switching frequency.

Claim 20 (Currently amended): The high-frequency heating apparatus according to claim

[[15]] 19, wherein the dead time generation circuit fixes or marginally increases the dead time at

a switching frequency not higher than a predetermined frequency.

Claim 21 (Currently amended): The high-frequency heating apparatus according to claim

[[15]] 19, wherein the dead time generation circuit suddenly increases the dead time at a

switching frequency not lower than a predetermined frequency.

Claim 22 (Previously presented): The high-frequency heating apparatus according to

claim 2, wherein the dead time generation circuit generates a dead time based on positive and

negative offset voltages each varying with a first inclination in proportion to increase of a

switching frequency and varying with a second inclination when the switching frequency reaches

a predetermined frequency or higher.

Page 9 of 18

Claim 23 (Previously presented): The high-frequency heating apparatus according to

claim 2, wherein the dead time generation circuit includes a VCC power supply, a duty control

power supply, a first current varying in proportion to a switching frequency, a second current

beginning to flow at a predetermined frequency and varying in proportion to the switching

frequency, a third current obtaining by and multiplying a combining current of the two currents

by a predetermined coefficient, and a upper and lower potential generation unit for generating

two upper and lower potentials obtained by adding positive and negative offset voltages

proportional to the third current, to the duty control power supply respectively, and a dead time is

generated based on the two upper and lower potentials.

Claim 24 (Previously presented): The high-frequency heating apparatus according to

claim 3, further comprising:

an error signal generation circuit for generating an error signal from a difference between

an input current of the AC power supply and a reference current; and

a frequency-modulated signal generation circuit for correcting a rectified voltage/rectified

current obtained by rectifying the AC power supply, based on an output (error signal) of the error

signal generation circuit, an output of the frequency-modulated signal generation circuit being

supplied to the dead time generation circuit;

wherein a lowest frequency limiting circuit is inserted between the frequency-modulated

signal generation circuit and the dead time generation circuit, the lowest frequency limiting

circuit supplies a limited frequency to the dead time generation circuit based on the output signal

of the frequency-modulated signal generation circuit so that a set frequency of the lowest

frequency limiting circuit is set to be higher than the output of the frequency-modulated signal

Page 10 of 18

generation circuit at the beginning of operation of the aforementioned high-frequency heating

apparatus, and in accordance with time having passed since the beginning of operation, the

limited frequency is lowered gradually, while with lowering of the limited frequency, a signal

higher in switching frequency of the limited frequency and the output signal of the frequency-

modulated signal generation circuit is selected as a signal to be supplied to the dead time

generation circuit in accordance with time having passed, so that the selected signal is changed

over gradually to the output signal of the frequency-modulated signal generation circuit.

Claim 25 (Currently amended): The high-frequency heating apparatus according to claim

[[20]] 24, wherein the lowest frequency limiting circuit has a capacitor, the capacitor is charged

during suspension of the high-frequency heating apparatus, and as soon as the high-frequency

heating apparatus begins to operate, a voltage of the capacitor is supplied to the dead time

generation circuit, and charges accumulated in the capacitor are discharged.

Claim 26 (Currently amended): The high-frequency heating apparatus according to claim

[[20]] 24, wherein the dead time generation circuit generates a fixed or marginally increased

dead time regardless of a switching frequency.

Claim 27 (Previously presented): The high-frequency heating apparatus according to

claim 3, wherein the dead time generation circuit generates a dead time increased in accordance

with increase of a switching frequency.

Page 11 of 18

Claim 28 (Currently amended): The high-frequency heating apparatus according to claim

[[23]] 27, wherein the dead time generation circuit fixes or marginally increases the dead time at

a switching frequency not higher than a predetermined frequency.

Claim 29 (Currently amended): The high-frequency heating apparatus according to claim

[[23]] 27, wherein the dead time generation circuit suddenly increases the dead time at a

switching frequency not lower than a predetermined frequency.

Claim 30 (Previously presented): The high-frequency heating apparatus according to

claim 3, wherein the dead time generation circuit generates a dead time based on positive and

negative offset voltages each varying with a first inclination in proportion to increase of a

switching frequency and varying with a second inclination when the switching frequency reaches

a predetermined frequency or higher.

Claim 31 (Previously presented): The high-frequency heating apparatus according to

claim 3, wherein the dead time generation circuit includes a VCC power supply, a duty control

power supply, a first current varying in proportion to a switching frequency, a second current

beginning to flow at a predetermined frequency and varying in proportion to the switching

frequency, a third current obtaining by and multiplying a combining current of the two currents

by a predetermined coefficient, and a upper and lower potential generation unit for generating

two upper and lower potentials obtained by adding positive and negative offset voltages

proportional to the third current, to the duty control power supply respectively, and a dead time is

generated based on the two upper and lower potentials.

Page 12 of 18